

ST178P

● Features

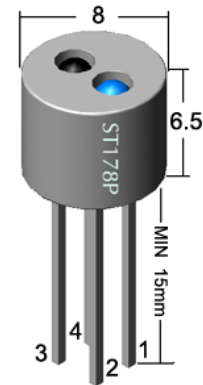
- Combines high output GaAs IRED with high sensitive phototransistor.
- Wide detecting range: 4~10mm.
- Non-contact detecting manner

● Applications

- IC card electric power meter.
- AMR system.
- Water meter.

● Dimensions Unit:mm;

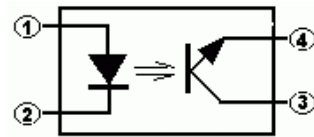
Unless otherwise specified, the tolerances are $\pm 0.2\text{mm}$



● Absolute Maximum Ratings(Ta=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward Current	I_F	50	mA
	Reverse Voltage	V_R	6	V
	Power Dissipation	P	75	mW
Output	Collector-Emitter Voltage	V_{CEO}	25	V
	Emitter-Collector Voltage	V_{ECO}	6	V
	Collector Power Dissipation	P_C	50	mW
*Operating Temperature		T_{opr}	-20~65	°C
Storage Temperature		T_{stg}	-30~75	°C
** Soldering Temperature		T_{sol}	260	°C

Internal Circuit



*The special requirement could be met according to customer's request.

**Soldering time: 5s max. Soldering position: at least 1.5mm from the base of the package.

● Electro-Optical Characteristics(Ta=25°C)

Parameter		Symbol	Test Condition	Min.	Typ.	Max.	Unit	
Input	Forward Voltage	V_F	$I_F=20\text{mA}$	-	1.25	1.5	V	
	Reverse Current	I_R	$V_R=3\text{V}$	-	-	10	μA	
Output	Collector Dark Current	I_{CEO}	$V_{CE}=20\text{V}$	-	-	1.0	μA	
	Collector Light Current	I_L	$V_{CE}=5\text{V}$ $I_F=8\text{mA}$	L3	0.3	-	-	mA
				L4	0.4	-	-	mA
				L5	0.5	-	-	mA
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_F=8\text{mA}$ $I_C=0.15\text{mA}$	-	-	0.4	V		
Transfer Character-istics	Response Time	Rise Time	T_r	-	10	-	μS	
		Fall Time	T_f	-	10	-	μS	

Notes: Collector light current I_L , Collector-emitter saturation voltage $V_{CE(SAT)}$, Relative current, Response time are measured within 2~5mm between photointerrupter's top and reflecting surface. The value is affected by the smooth of light reflecting surface.